

200mW, NPN Small Signal Transistor

FEATURES

- Epitaxial planar die construction
- Surface mount device type
- Moisture sensitivity level 1
- Matte Tin(Sn) lead finish with Nickel(Ni) under plate
- Pb free and RoHS compliant
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21





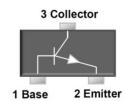


MECHANICAL DATA

- Case: SOT- 23 small outline plastic package

- Terminal: Matte tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed - High temperature soldering guaranteed: 260°C/10s

- Weight: 8mg (approximately)



SOT-23

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)				
PARAM	ETER	SYMBOL	VALUE	UNIT
Power dissipation		P _D	200	mW
	BC846		80	
Collector-Base Voltage	BC847	V _{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V _{CEO}	45	V
	BC848		30	
	BC846		6	
Emitter-Base Voltage	BC847	V _{EBO}	6	V
	BC848		5	
Collector Current		I _C	0.1	А
Junction and Storage Temperature Range		T_{J}, T_{STG}	-55 to +150	°C
Notes: 1 Valid provided that electrodes	are kent at ambient temperatu	re		l .

Notes: 1. Valid provided that electrodes are kept at ambient temperature

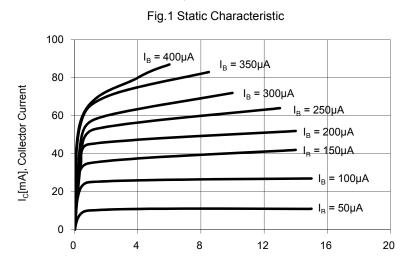
PAF	RAMETER			SYMBOL	MIN	MAX	UNIT
	BC846				80		
Collector-Base Breakdown Voltage	BC847	I_C = 10 μ A	I _E = 0	$V_{(BR)CBO}$	50	-	V
	BC848				30	1	
	BC846				65		
Collector-Emitter Breakdown Voltag	je BC847	I_C = 10mA	$I_B = 0$	$V_{(BR)CEO}$	45	-	V
	BC848				30	1	
	BC846				6		
Emitter-Base Breakdown Voltage	BC847	I _E = 1μA	$I_C = 0$	$V_{(BR)EBO}$	6	-	V
	BC848				5	1	
Collector Cut-off Current		V _{CB} = 30V	I _E = 0	I _{CBO}	-	100	nA
Emitter Cut-off Current		V _{EB} = 5 V	I _C =0	I _{EBO}	-	0.1	μA
BC846A, BC	C847A, BC848A				110	220	
DC Current Gain BC846B, BC	847B, BC848B	V_{CE} = 5 V	I_C = 2mA	h_{FE}	200	450	
BC8470	C, BC848C				420	800	
Collector-Emitter Saturation Voltage	I _C = 100mA	I _B = 5mA	V _{CE(sat)}	-	0.5	V	
Base-Emitter Saturation Voltage	I _C = 100mA	I _B = 5mA	V _{BE(sat)}	-	1.1	V	
Transition frequency	V _{CE} = 5V	I _C = 10 mA	f= 100MHz		100	-	MHz

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RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)



V_{CE}[V], Collector-Emitter Voltage

Fig.3 Base-Emitter Saturation Voltage

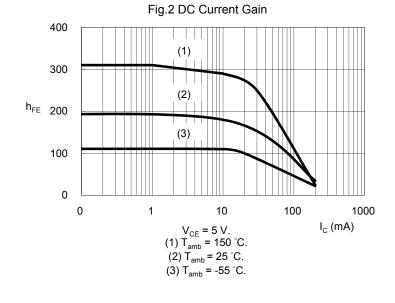
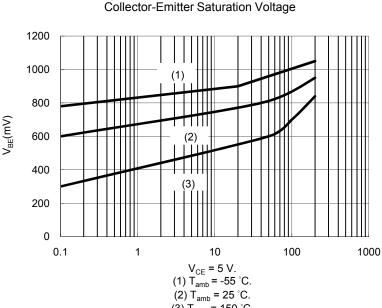
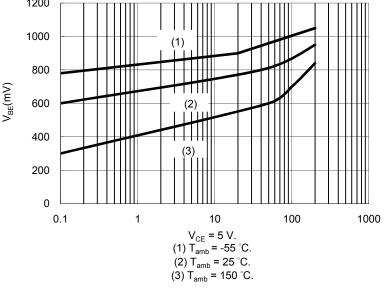
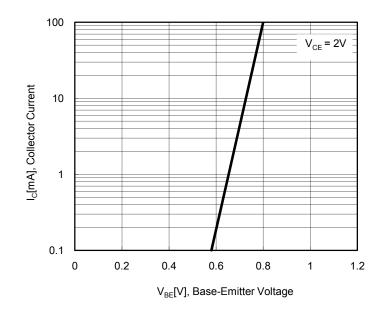
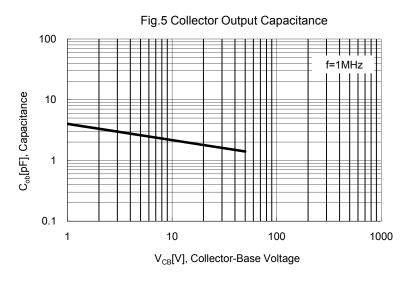


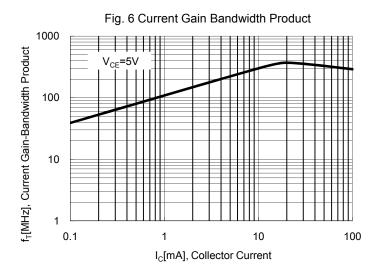
Fig. 4 Base-Emitter On Voltage











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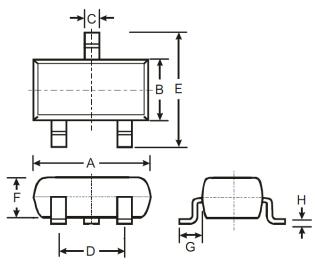
ORDERING INFORMATION				
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
BC84xx	RF	G	SOT-23	3K / 7" Reel
(Note 1)	R5	9	301-23	10K / 13" Reel

Note 1: "xx" is device code from "BC846A" ~ "BC848C", detail could follow the previous page

EXAMPLE				
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
BC846A RFG	BC846A	RF	G	Green compound

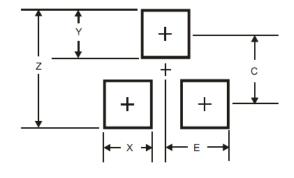
DIMENSIONS

SOT-23



DIM.	Unit (mm)		Unit (inch)	
DIIVI.	Min	Max	Min	Max
Α	2.70	3.10	0.106	0.122
В	1.10	1.50	0.043	0.059
С	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
Е	2.10	2.64	0.083	0.104
F	0.89	1.30	0.035	0.051
G	0.55 REF		0.022	REF
Н	0.1 REF		0.004	REF

SUGGEST PAD LAYOUT



DIM.	Unit (mm)	Unit (inch)
DIIVI.	Тур.	Тур.
Z	2.90	0.114
Χ	0.80	0.031
Υ	0.90	0.035
С	2.00	0.079
Е	1.35	0.053

MARKING CODE

PART NO.	MARKING
BC846A	1A
BC846B	1B
BC847A	1E
BC847B	1F
BC847C	1G
BC848A	1J
BC848B	1K
BC848C	1L

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